XP132A1635SR



ETR1110_001a

Power MOSFET

■GENERAL DESCRIPTION

The XP132A1635SR is a P-channel Power MOSFET with low on-state resistance and ultra high-speed switching characteristics.

Because high-speed switching is possible, the IC can be efficiently set thereby saving energy.

The small SOP-8 package makes high density mounting possible.

■APPLICATIONS

- ●Notebook PCs
- Cellular and portable phones
- On-board power supplies
- Li-ion battery systems

■FEATURES

Low On-State Resistance : Rds(on)= 0.033Ω (Vgs=-4.5V)

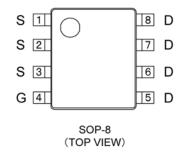
: Rds(on)= 0.055Ω (Vgs=-2.5V)

Ultra High-Speed Switching Driving Voltage : -2.5V **P-Channel Power MOSFET**

DMOS Structure

Package : SOP-8

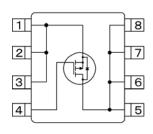
■PIN CONFIGURATION



■ PIN ASSIGNMENT

PIN NUMBER	PIN NAME	FUNCTION
1~3	S	Source
4	G	Gate
5~8	D	Drain

■EQUIVALENT CIRCUIT



P-channel MOSFET (1 device built-in)

■ ABSOLUTE MAXIMUM RATINGS

Ta = 25						
PARAMETER	SYMBOL	RATINGS	UNITS			
Drain-Source Voltage	Vdss	-20	V			
Gate-Source Voltage	Vgss	±12	V			
Drain Current (DC)	ld	-8	Α			
Drain Current (Pulse)	ldp	-32	Α			
Reverse Drain Current	ldr	-8	Α			
Channel Power Dissipation *	Pd	2.5	W			
Channel Temperature	Tch	150	ပ္			
Storage Temperature Range	Tstg	-55~150	လူ			

^{*} When implemented on a glass epoxy PCB

■ELECTRICAL CHARACTERISTICS

DC Characteristics

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Drain Cut-Off Current	ldss	Vds=-20V, Vgs=0V	-	-	-10	μΑ
Gate-Source Leak Current	lgss	Vgs=±12V, Vds=0V	-	-	±1	μΑ
Gate-Source Cut-Off Voltage	Vgs(off)	ld=-1mA, Vds=-10V	-0.5	-	-1.2	V
Drain-Source On-State Resistance *	Rds(on)	Id=-4A, Vgs=-4.5V	-	0.025	0.033	Ω
Drain-Source On-State Resistance		Id=-4A, Vgs=-2.5V	-	0.040	0.055	Ω
Forward Transfer Admittance *	Yfs	Id=-4A, Vds=-10V	-	16	-	S
Body Drain Diode Forward Voltage	Vf	If=-8A, Vgs=0V	-	-0.85	-1.1	V

^{*} Effective during pulse test.

Dynamic Characteristics

Ta = 25°C

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Input Capacitance	Ciss	Vds=-10V, Vgs=0V f=1MHz	-	1700	-	pF
Output Capacitance	Coss		1	1000	1	pF
Feedback Capacitance	Crss			500		pF

Switching Characteristics

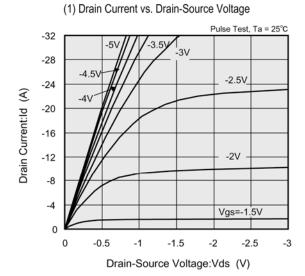
Ta = 25°C

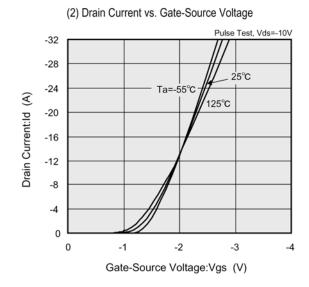
PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Turn-On Delay Time	td (on)	Vgs=-5V, Id=-4A Vdd=-10V	ı	15	ı	ns
Rise Time	tr		-	45	-	ns
Turn-Off Delay Time	td (off)		-	70	-	ns
Fall Time	tf		-	65	-	ns

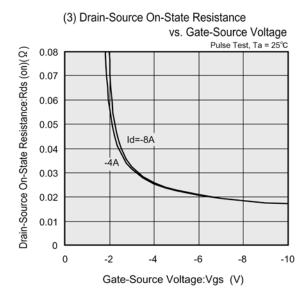
Thermal Characteristics

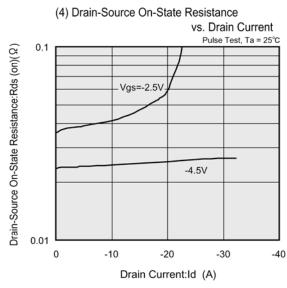
PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Thermal Resistance (Channel-Ambience)	Rth (ch-a)	Implement on a glass epoxy resin PCB	-	50	-	°C/W

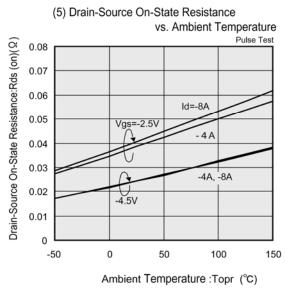
■TYPICAL PERFORMANCE CHARACTERISTICS

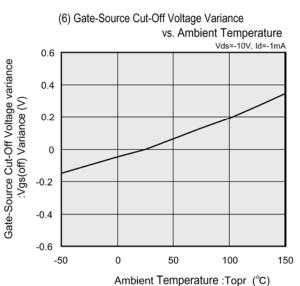




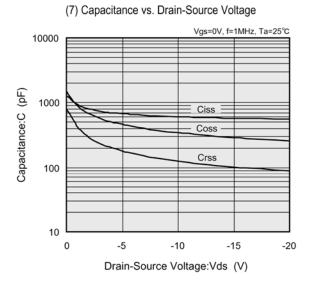


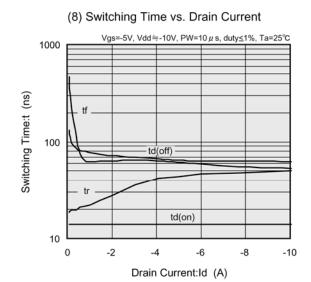


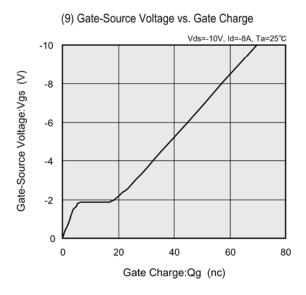


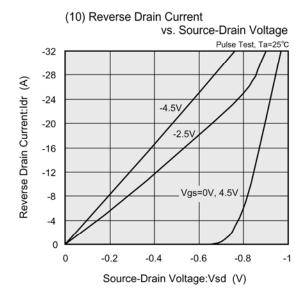


■TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

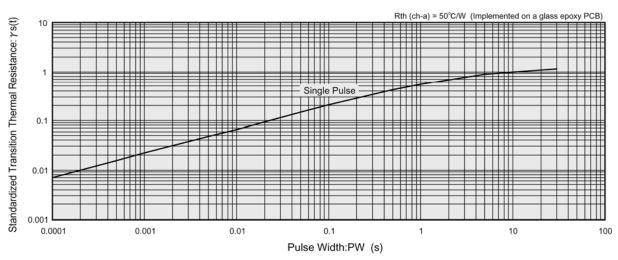








(11) Standardized transition Thermal Resistance vs. Pulse Width



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